Features

- Zero Forward/Reverse Recovery Current
- High Blocking Voltage
- High Frequency Operation
- Positive Temperature Coefficient on V_F
- Temperature Independent Switching Behavior
- High surge current capability



TO-220-2

Benefits

- Higher System Efficiency
- Parallel Device Convenience without thermal runaway
- Higher Temperature Application
- No Switching loss
- Hard Switching & Higher Reliability
- Environmental Protection

Applications

- PC Power
- Server Power Supply
- AC/DC converters
- DC/DC converters
- Uninterruptable power supplies



Maximum Ratings (T_C=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Value	Unit
Peak Repetitive Reverse Voltage	V_{RRM}		650	V
Peak Reverse Surge Voltage	V_{RSM}		650	V
DC Blocking Voltage	V_R		650	V
Continuous Forward Current	I_F	T_C=25°C T_C=135°C T_C=150°C	32 14 10	A
Non repetitive Forward Surge Current	I_{FSM}	T_C = 25°C, t_p=10 ms, Half Sine Pulse T_C = 150°C, t_p=10 ms, Half Sine Pulse T_C = 25°C, t_p=10 µs, Square	65 55 520	A
Repetitive peak Forward Surge Current	I_{FRM}	T_C = 25°C, t_p=10 ms, Freq = 0.1Hz, 100 cycles, Half Sine Pulse T_C = 150°C, t_p=10 ms, Freq = 0.1Hz, 100 cycles, Half Sine Pulse	55 45	A
Total power dissipation	P_D	T_C=25°C	94	W
Operating Junction Temperature	T_J		-55 to 175	°C
Storage Temperature	T_{STG}		-55 to 175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Electrical Characteristics

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
DC Blocking Voltage	V_{DC}	I_R = 250μA,T_J = 25°C	650			V
Forward Voltage	V_F	I_F = 10A, T_J = 25°C		1.45	1.8	V
		I_F = 10A, T_J = 125°C		1.6		
		I_F = 10A, T_J = 175°C		1.7		V
Reverse Current	I_R	V_R = 650V, T_J = 25°C		12	80	uA
		V_R = 650V, T_J = 125°C		68		uA
		V_R = 650V, T_J = 175°C		190		uA
Total Capacitive Charge	Q_C	V_R = 400V T_J = 25°C		23		nC
Total Capacitance	C	V_R = 1V, T_J = 25°C, Freq = 1MHz		380		pF
		V_R = 200V, T_J = 25°C, Freq = 1MHz		48		
		V_R = 400V, T_J = 25°C, Freq = 1MHz		31		

Note: This is a majority carrier diode, so there is no reverse recovery charge

Thermal Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Thermal Resistance	$R_{th(j-c)}$	junction-case		1.6		^{0}C/W

Ordering Information

Order number	Package	Marking	Operation Temperature Range	MSL Grade	Ship,Quantity	Green
SIDH10SG60CXKSA2	TO-220-2	SC6D10065A	-55 to 175°C	1	TUBE,1000	Rohs

Typical Electrical Curves

Figure 1. Forward Characteristics

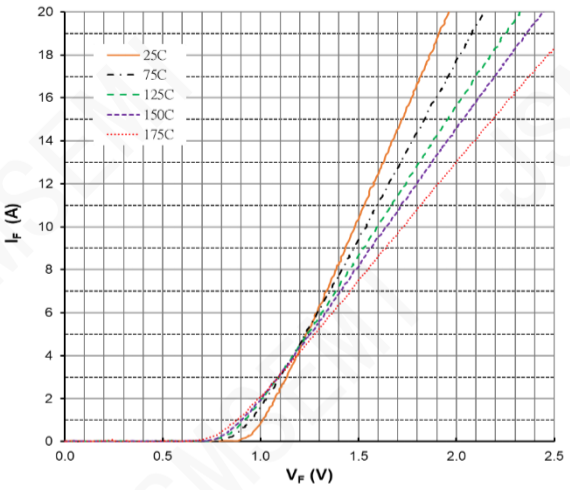


Figure 2. Forward Characteristics

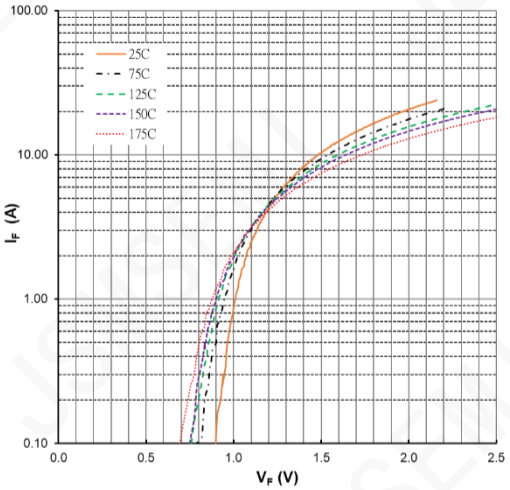


Figure 3. Reverse Characteristics

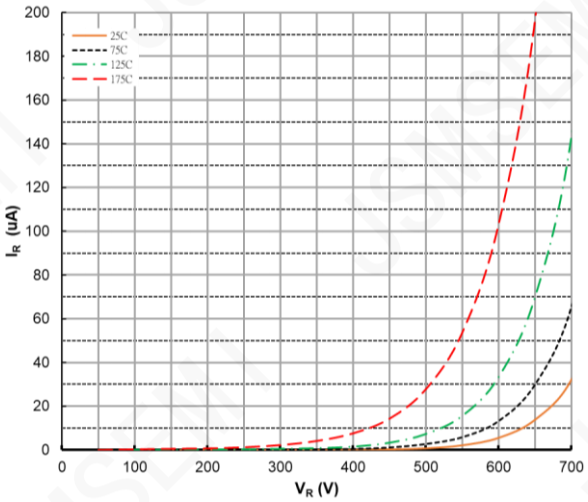


Figure 4. Power Derating

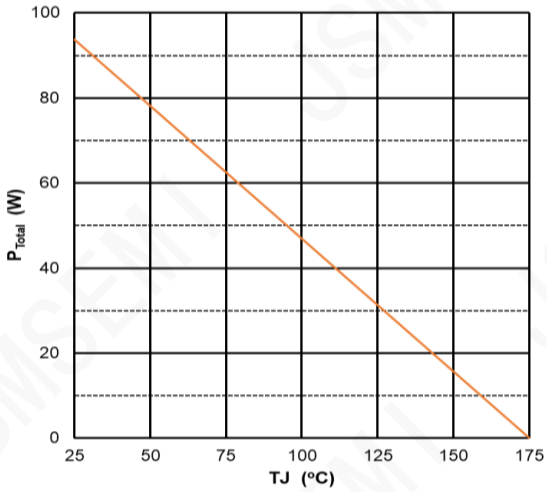


Figure 5. Capacitance vs Reverse Voltage

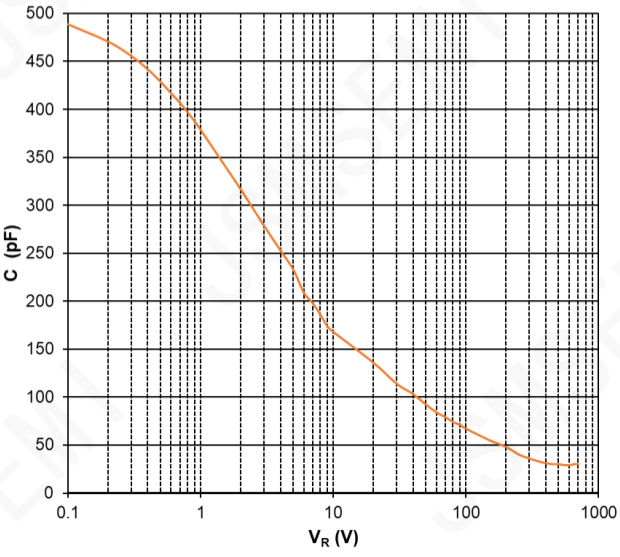
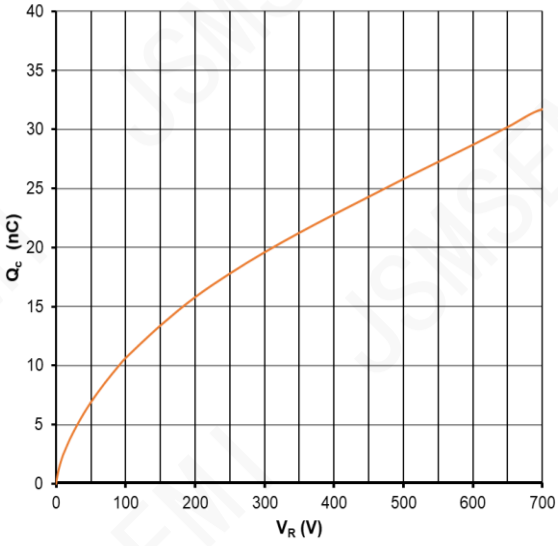
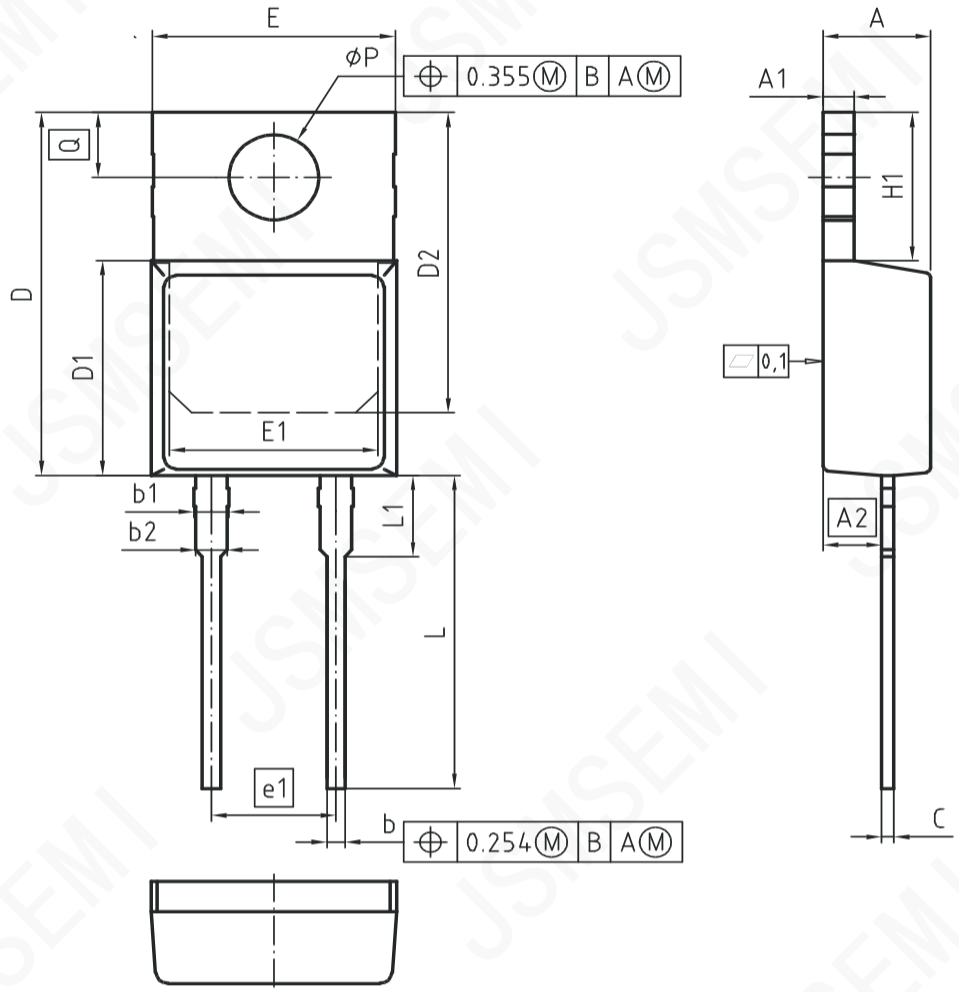


Figure 6. Recovery Charge vs Reverse Voltage



Package Dimensions

(TO-220-2 Package)



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.30	4.50	0.169	0.177
A1	1.17	1.37	0.046	0.054
A2	2.30	2.50	0.091	0.098
b	0.65	0.85	0.026	0.033
b1	1.19	1.69	0.047	0.066
b2	1.19	1.39	0.047	0.055
c	0.40	0.60	0.016	0.024
D	15.35	15.95	0.604	0.628
D1	9.05	9.45	0.356	0.372
D2	12.30	13.05	0.484	0.514
E	9.80	10.20	0.386	0.402
E1	7.25	8.60	0.285	0.339
e1	5.08		0.200	
N	2		2	
H1	5.90	6.90	0.232	0.272
L	13.00	14.00	0.512	0.551
L1	3.30	3.70	0.130	0.146
øP	3.55	3.90	0.140	0.146
Q	2.60	3.00	0.102	0.118

Revision History

Rev.	Change	Date
V1.0	Initial version	2/23/2022

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